L	Hits	Search Text	DB	Time stamp
Number				0004/00/00
1	2617	<pre>((((wiring near (layer film)) with (hole plug)) and (gate and source and drain) and ((insulat\$3 dielectric) near (layer film))) and (substrate wafer))</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/08/02 18:10
2	479	plug)) and (gate and source and drain) and ((insulat\$3 dielectric) near (layer film))) and (substrate wafer)) ) and	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/08/02 18:10
3	1340	<pre>(dielectric near constant)  (((((wiring near (layer film)) with (hole plug)) and (gate and source and drain)  and ((insulat\$3 dielectric) near (layer  film))) and (substrate wafer)) ) and  concentration</pre>	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/08/02 18:10